



## MICROCIRCUIT DATA SHEET

**MNLM1575-15-X REV 0D1**

Original Creation Date: 08/29/95  
Last Update Date: 05/22/00  
Last Major Revision Date: 08/29/95

### SIMPLE SWITCHER(TM) 1A STEP-DOWN VOLTAGE REGULATOR

#### General Description

The LM1575 regulator is a monolithic integrated circuit that provides all the active functions for a step-down (buck) switching regulator, capable of driving a 1A load with excellent line and load regulation.

Requiring a minimum number of external components, this regulator is simple to use and includes internal frequency compensation and a fixed-frequency oscillator.

The LM1575 offers a high-efficiency replacement for popular three-terminal linear regulators. It substantially reduces the size of the heat sink, and in many cases no heat sink is required.

A standard series of inductors optimized for use with the LM1575 are available from several different manufacturers. This feature greatly simplifies the design of switch-mode power supplies.

Other features include a guaranteed  $\pm 4\%$  tolerance on output voltage within specified input voltage and output load conditions, and  $\pm 10\%$  on the oscillator frequency. External shutdown is included, featuring 50 $\mu$ A (typical) standby current. The output switch includes cycle-by-cycle current limiting, as well as thermal shutdown for full protection under fault conditions.

#### Industry Part Number

LM1575-15

#### NS Part Numbers

LM1575J-15-QML  
LM1575K-15-QML  
LM1575WG-15-QML

#### Prime Die

LM1575-15

#### Controlling Document

SEE FEATURES SECTION

#### Processing

MIL-STD-883, Method 5004

#### Quality Conformance Inspection

MIL-STD-883, Method 5005

#### Subgrp Description

#### Temp ( °C)

1	Static tests at	+25
2	Static tests at	+125
3	Static tests at	-55
4	Dynamic tests at	+25
5	Dynamic tests at	+125
6	Dynamic tests at	-55
7	Functional tests at	+25
8A	Functional tests at	+125
8B	Functional tests at	-55
9	Switching tests at	+25
10	Switching tests at	+125
11	Switching tests at	-55

## **Features**

- Adjustable version output voltage range, 1.23V to 37V  $\pm 4\%$  max over line and load conditions
- Guaranteed 1A output current
- Requires only 4 external components
- 52KHz fixed frequency internal oscillator
- TTL shutdown capability, low power standby mode
- High efficiency
- Uses readily available standard inductors
- Thermal shutdown and current limit protection

### CONTROLLING DOCUMENTS:

LM1575J-15-QML	5962-9167401QEA
LM1575K-15-QML	5962-9167401QXA
LM1575WG-15-QML	5962-9167401QZA

## **Applications**

- Simple high-efficiency step-down (buck) regulator
- Efficient pre-regulator for linear regulators
- On-card switching regulators
- Positive to negative converted (Buck-Boost)

**(Absolute Maximum Ratings)**

(Note 1)

Maximum Supply Voltage	45V
ON/OFF Pin Input Voltage	-0.3V $\leq$ V $\leq$ +Vin
Output Voltage to Ground (Steady State)	-1V
Power Dissipation (Note 2, 3)	Internally Limited
Storage Temperature Range	-65 C $\leq$ Ta $\leq$ +150 C
Lead Temperature (Soldering, 10 seconds)	
METAL CAN	300 C
CERDIP	260 C
CERAMIC SOIC	260 C
Maximum Junction Temperature	150 C
Thermal Resistance	
ThetaJA	
METAL CAN (Still Air) (500LF/Min Air Flow)	45 C/W
CERDIP (Still Air) (500LF/Min Air Flow)	10 C/W
CERAMIC SOIC (Still Air) (500LF/Min Air Flow)	70 C/W
	33 C/W
	121 C/W
	73 C/W
Theta JC (Note 3)	
METAL CAN	3.3 C/W
CERDIP	2.0 C/W
CERAMIC SOIC	3.0 C/W
Package Weight (Typical)	
METAL CAN	TBD
CERDIP	TBD
CERAMIC SOIC	TBD
ESD Tolerance (Note 4)	3000V

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

Note 2: The maximum power dissipation must be derated at elevated temperatures and is dictated by  $T_{jmax}$  (maximum junction temperature),  $\Theta_{JA}$  (package junction to ambient thermal resistance), and  $TA$  (ambient temperature). The maximum allowable power dissipation at any temperature is  $P_{dmax} = (T_{jmax} - TA)/\Theta_{JA}$  or the number given in the Absolute Maximum Ratings, whichever is lower.

**(Continued)**

Note 3: The package material for these devices allows much improved heat transfer over our standard ceramic packages. In order to take full advantage of this improved heat transfer, heat sinking must be provided between the package base (directly beneath the die), and either metal traces on, or thermal vias through, the printed circuit board. Without this additional heat sinking, device power dissipation must be calculated using junction-to-ambient, rather than junction-to-case, thermal resistance. It must not be assumed that the device leads will provide substantial heat transfer out of the package, since the thermal resistance of the leadframe material is very poor, relative to the material of the package base. The stated junction-to-case thermal resistance is for the package material only, and does not account for the additional thermal resistance between the package base and the printed circuit board. The user must determine the value of the additional thermal resistance and must combine this with the stated value for the package, to calculate the total allowed power dissipation for the device.

Note 4: Human body model, 1.5k Ohms in series with 100pF.

**Recommended Operating Conditions**

Temperature Range	-55 C ≤ Ta ≤ +125 C
Supply Voltage	40V

## Electrical Characteristics

### ELECTRICAL CHARACTERISTICS: SYSTEM PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)  
 DC: Vin = 30V, and Iload = 200mA.

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
Vout	Output Voltage		1		14.85	15.15	V	1
		0.2A ≤ Iload ≤ 1A, 18V ≤ Vin ≤ 40V	1		14.55	15.45	V	1
			1		14.40	15.60	V	2, 3

### ELECTRICAL CHARACTERISTICS: DEVICE PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)  
 DC: Vin = 30V, and Iload = 200mA.

Vsat	Saturation Voltage	Iout = 1A	2			1.2	V	1
			2			1.4	V	2, 3
Icl	Current Limit	Peak Current, tON ≤ 3μS	2		1.7	3.0	A	1
			2		1.3	3.2	A	2, 3
Il	Output Leakage Current	Vin = 35V, Output = 0V	4			2	mA	1
		Vin = 35V, Output = -1V	4			30	mA	1
Iq	Quiescent Current		4			10	mA	1
			4			12	mA	2, 3
Istby	Standby Quiescent Current	ON/OFF Pin = 5V (OFF)				200	uA	1
						500	uA	2, 3

### AC ELECTRICAL CHARACTERISTICS: DEVICE PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)  
 AC: Vin = 30V, and Iload = 200mA.

fo	Oscillator Frequency				47	58	KHz	4
					43	62	KHz	5, 6
Dc	Max Duty Cycle (ON)		3		93		%	9

## Electrical Characteristics

### ELECTRICAL CHARACTERISTICS: ON/OFF CONTROL

(The following conditions apply to all the following parameters, unless otherwise specified.)  
 DC: Vin = 30V, and Iload = 200mA.

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
Vih	ON/OFF Pin Logic Input Level	Vout = 0V			2.2		V	1
Vih	ON/OFF Pin Logic Input Level	Vout = 0V			2.4		V	2, 3
Vil	ON/OFF Pin Logic Input Level	Vout = 15V				1.0	V	1
Vil	ON/OFF Pin Logic Input Level	Vout = 15V				0.8	V	2, 3
Iih	ON/OFF Pin Input Current	ON/OFF Pin = 5V (OFF)				30	uA	1
Iil	ON/OFF Pin Input Current	ON/OFF Pin = 0V (ON)				10	uA	1

Note 1: External components such as the catch diode, inductor, input and output capacitors can affect switching regulator system performance.

Note 2: Output sourcing current. No diode, inductor or capacitor connected to output.

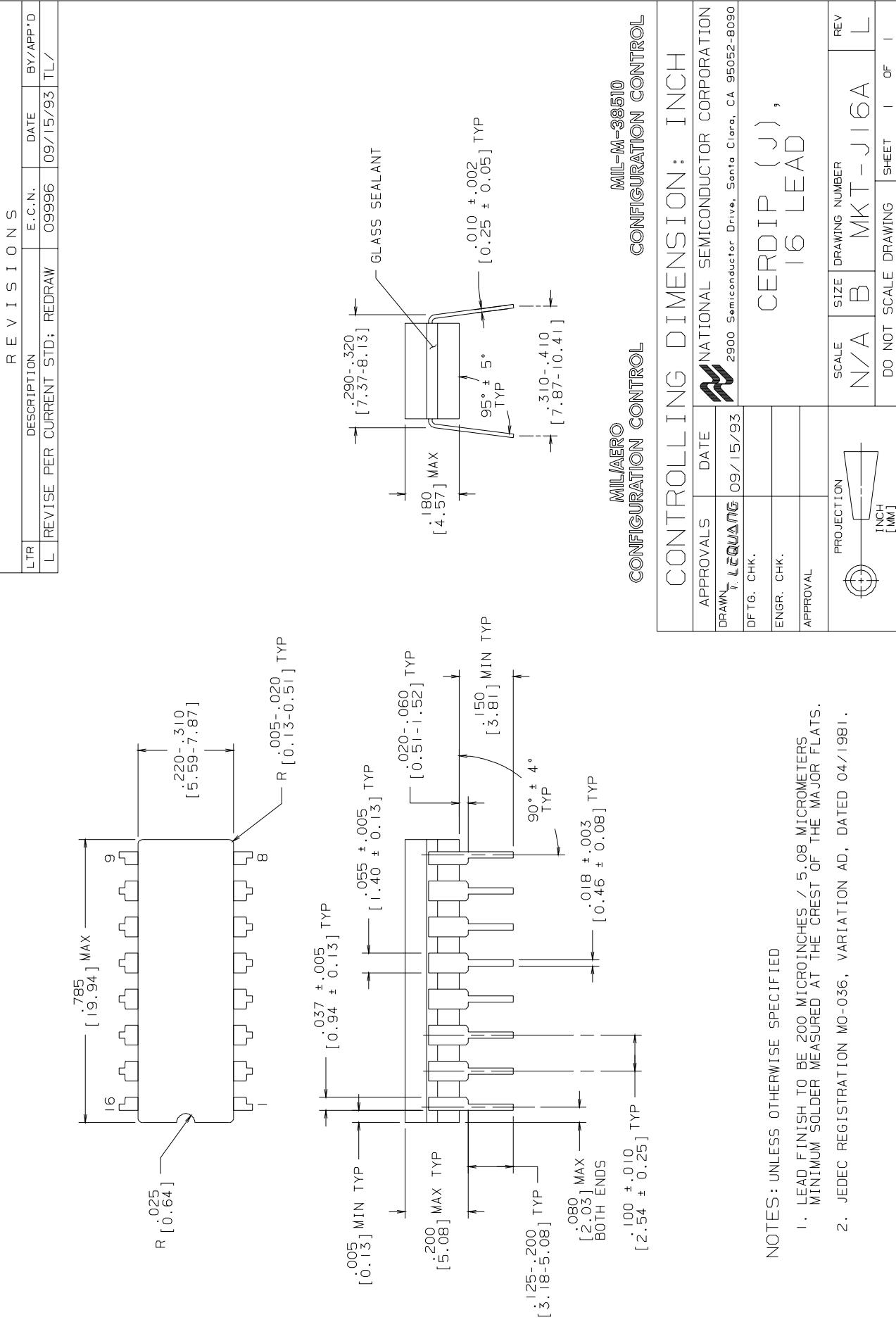
Note 3: Feedback removed from output and connected to 0V.

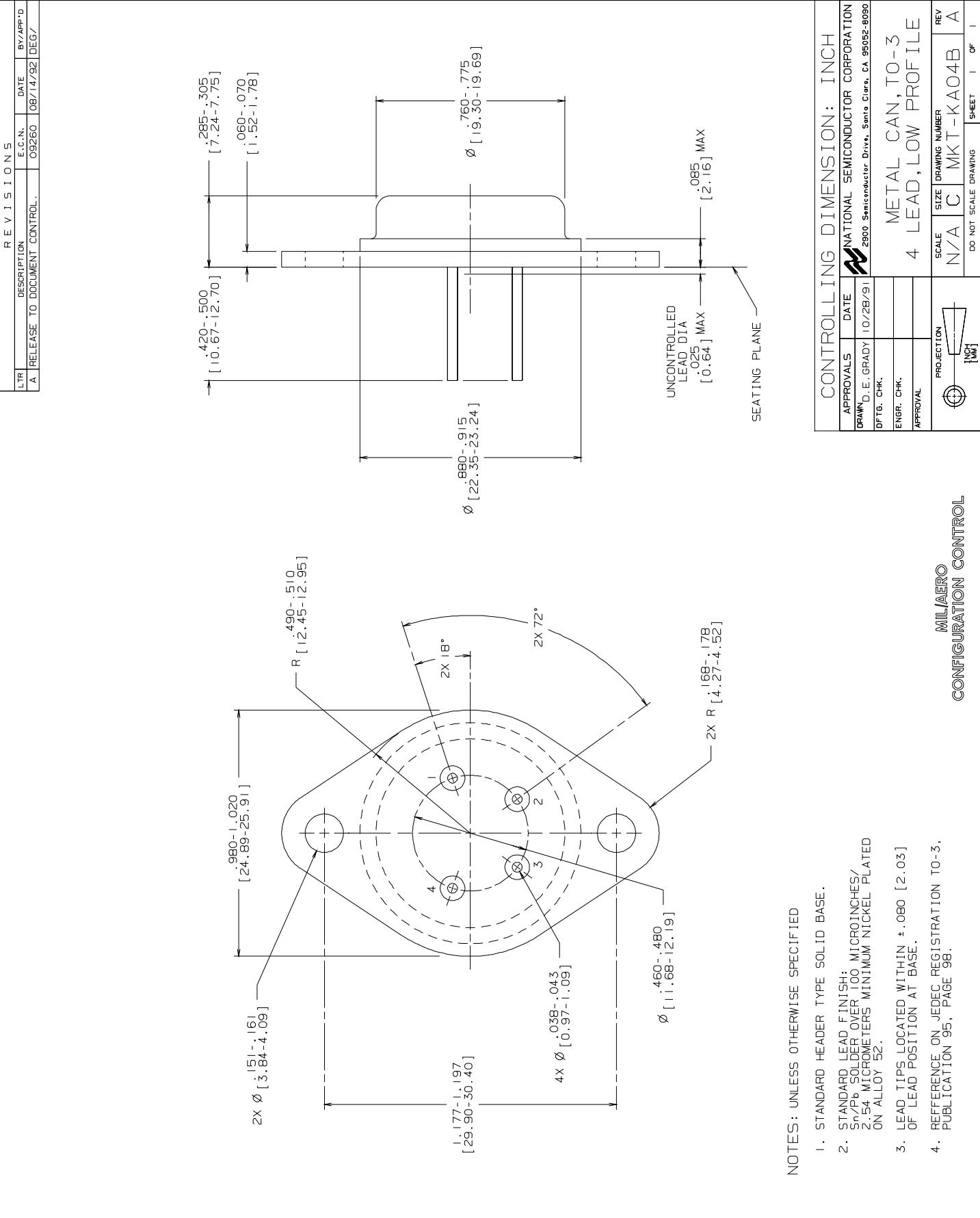
Note 4: Feedback removed from output and connected to 25V to force the output transistor OFF.

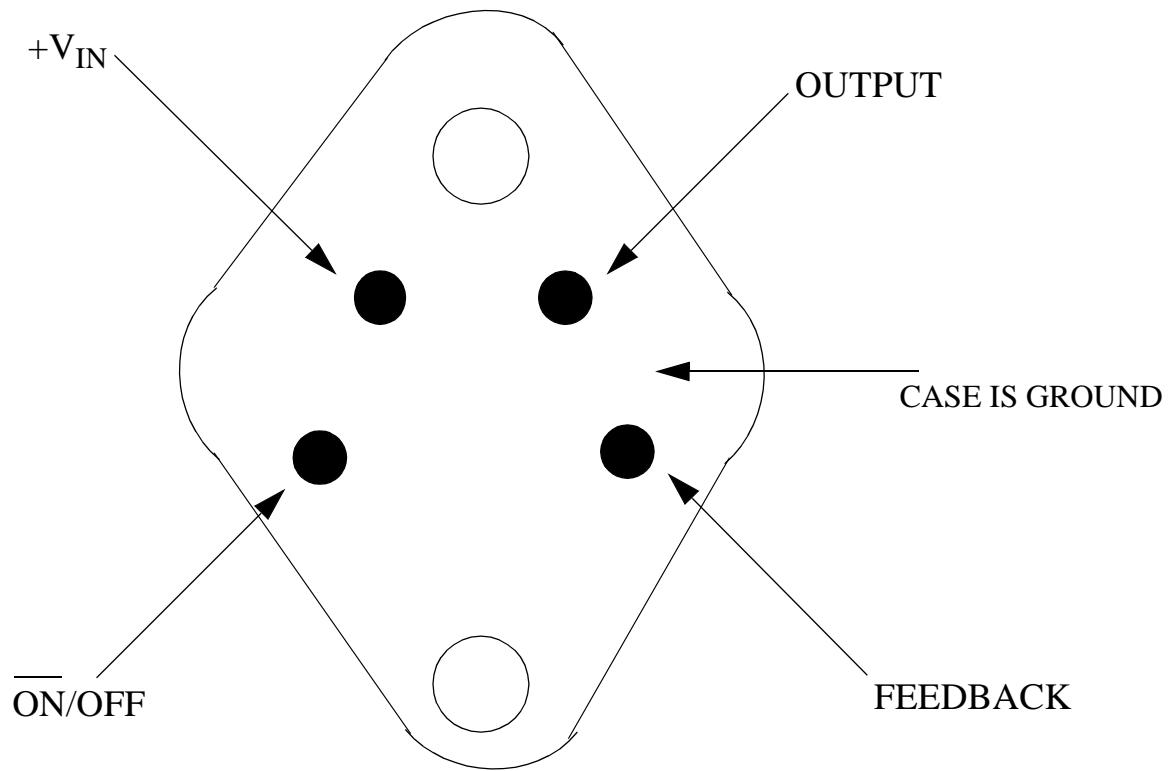
## Graphics and Diagrams

GRAPHICS#	DESCRIPTION
06153HRA2	METAL CAN (KA), TO-3, 4LD, LOW PROFILE (B/I CKT)
06265HRB2	CERDIP (J), 16 LEAD (B/I CKT)
06379HRA1	CERAMIC SOIC (WG), 16 LEAD (B/I CKT)
J16ARL	CERDIP (J), 16 LEAD (P/P DWG)
KA04BRA	METAL CAN (KA), TO-3, 4 LEAD, LOW PROFILE(P/P DWG)
P000232A	METAL CAN (KA), TO-3, 4LD, LOW PROFILE (PINOUT)
P000371A	CERDIP (J), 16 LEAD (PINOUT)
P000464A	CERAMIC SOIC (WG), 16 LEAD (PIN OUT)
WG16ARC	CERAMIC SOIC (WG), 16 LEAD (P/P DWG)

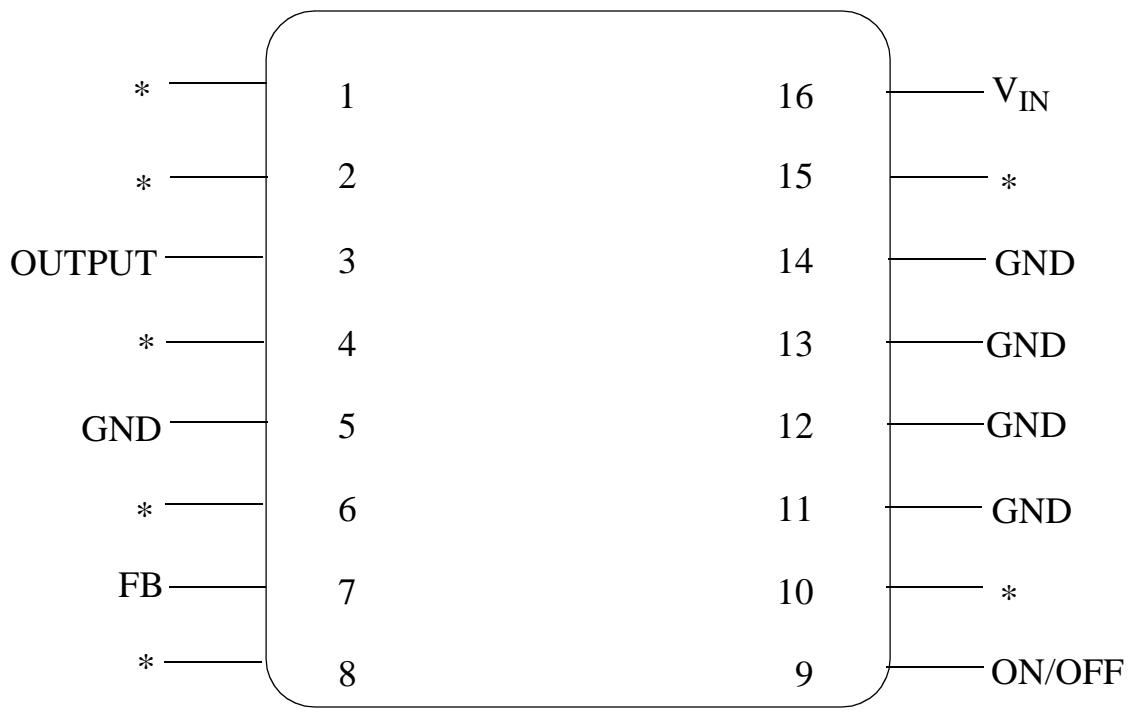
See attached graphics following this page.







**LM1575K, LM1575HVK**  
**4 - LEAD TO-3**  
**CONNECTION DIAGRAM**  
**BOTTOM VIEW**  
**P000232A**



\*No Internal Connection

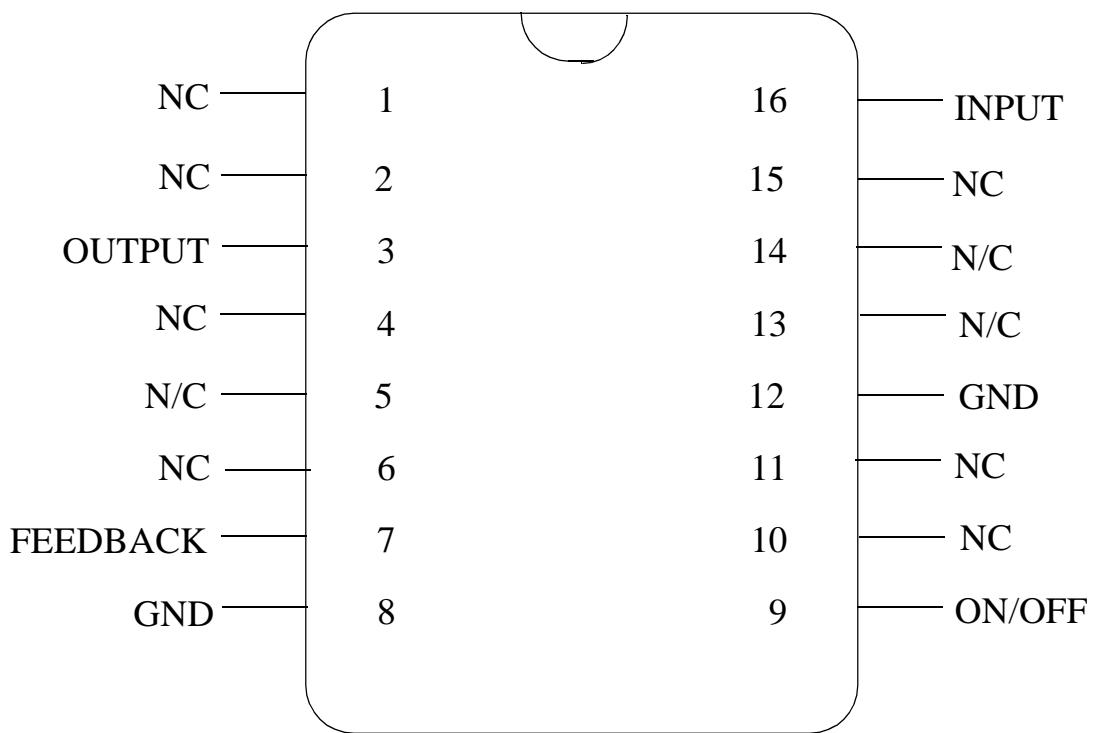
# LM1575J

## 16 - LEAD DIP

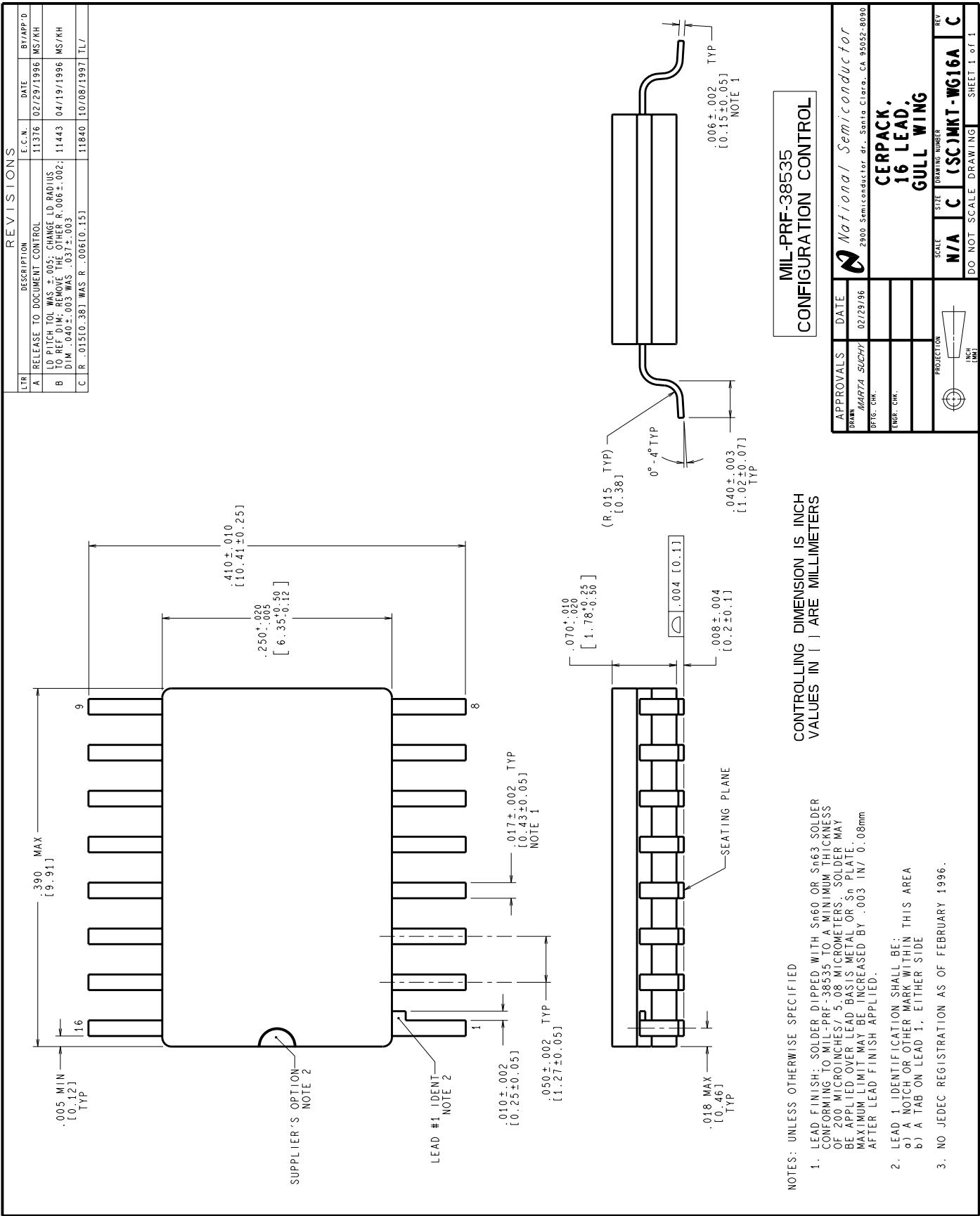
### CONNECTION DIAGRAM

### TOP VIEW

### P000371A



**LM1575WG**  
**16 - LEAD CERAMIC SOIC**  
**CONNECTION DIAGRAM**  
**TOP VIEW**  
**P000464A**



**Revision History**

<b>Rev</b>	<b>ECN #</b>	<b>Rel Date</b>	<b>Originator</b>	<b>Changes</b>
0C0	M0001550	05/22/00	Barbara Lopez	Changed: MNLM1575-X-15 Rev. 0B0 to MNLM1575-15-X Rev. 0C0. Added power dissipation note for Aluminum Nitride package. Changed nomenclature.
0D1	M0003689	05/22/00	Rose Malone	Update MDS: MNLM1575-15-X, Rev. 0C0 to MNLM1575-15-X, Rev. 0D1. Added reference to WG package to Main Table, Market Dwg., B/I Ckt., Pin Out to Graphics Section and to Absolute Maximum Ratings Section. Moved Controlling Documents (SMD numbers) to Features Section. Corrected typo in Recommended Operating Conditions Section.